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**2nd Sem / Comp, ECE IT, I & control , Mechatronics,  
Med. Eltx, Eltx & Instr., Power Eltx, EEE  
Subject:- Basic Electronics / Analog Elx.**

Time : 3Hrs.

M.M. : 100

### SECTION-A

**Note:** Multiple choice questions. All questions are compulsory (10x1=10)

- Q.1 Atomic number of Germanium is \_\_\_\_\_ (CO1)  
a) 12                                      b) 14  
c) 18                                      d) 32
- Q.2 In P type semiconductors, \_\_\_\_\_ are the minority carriers (CO1)  
a) Electrons                              b) Holes  
c) Both
- Q.3 Full wave rectifier has ripple factor value of \_\_\_\_\_ (CO2)  
a) 0.4                                      b) 0.8  
c) 1.2                                      d) 1.6
- Q.4 The knee voltage for Si is \_\_\_\_\_ volt (CO2)  
a) 0    b) 0.3  
c) 0.7                                      d) 1

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- Q.5 Donor type semiconductor is formed by adding impurity of valences \_\_\_\_\_ (CO1)  
a) 3    b) 4  
c) 5    d) 6
- Q.6 For buffers, the configuration of transistor used is \_\_\_\_\_ (CO3)  
a) CE    b) CB  
c) CC
- Q.7 In CE configuration, power gain is \_\_\_\_\_ (CO3)  
a) less than unity                      b) low  
c) medium                                  d) high
- Q.8 Thermal Runway can be avoided by checking the increase of \_\_\_\_\_ current with temperature. (CO4)  
a)  $I_C$     b)  $I_B$   
c)  $I_E$     d)  $I_{CBO}$
- Q.9 AFET has \_\_\_\_\_ terminals (CO6)  
a) 1    b) 2  
c) 3    d) 4
- Q.10 The FET has \_\_\_\_\_ (CO6)  
a) Large input impedance  
b) Large output impedance  
c) Large power gain  
d) High voltage gain

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### SECTION-B

**Note:** Objective type questions. All questions are compulsory. (10x1=10)

- Q.11 Define a covalent bond. (CO1)
- Q.12 Intrinsic semiconductors are \_\_\_\_\_(pure/impure). (CO1)
- Q.13 Draw the symbol of PNP transistor. (CO3)
- Q.14 Define an ideal diode. (CO2)
- Q.15 Define current gain in transistor? (CO3)
- Q.16 Define depletion layer. (CO2)
- Q.17 Write any one advantage of JFET. (CO6)
- Q.18 Define PIV in diodes. (CO2)
- Q.19 Define thermal runaway. (CO4)
- Q.20 Expand MOSFET. (CO6)

### SECTION-C

**Note:** Short answer type questions. Attempt any twelve questions out of fifteen questions. (12x5=60)

- Q.21 Draw & Explain the atomic structure of Silicon. (CO1)
- Q.22 How current flows in Intrinsic semiconductors. (CO1)
- Q.23 Draw half wave rectifier, what is its ripple factor? (CO2)
- Q.24 Draw & Explain diode characteristics. (CO2)
- Q.25 Compare CE & CC configuration. (CO3)

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- Q.26 Show how LC filter works? (CO2)
- Q.27 Draw & explain the output characteristics of CE configuration. (CO3)
- Q.28 Define Biasing of transistor, why it is needed? (CO4)
- Q.29 What is need of stabilization of operating point? (CO4)
- Q.30 Draw the circuit diagram of Single stage amplifier. (CO5)
- Q.31 Draw biasing arrangement with emitter feedback. Give its advantages. (CO4)
- Q.32 What are the advantages & applications of CMOS? (CO6)
- Q.33 Draw the clamper circuit, show its waveform. (CO2)
- Q.34 Explain in detail the "avalanche breakdown". (CO2)
- Q.35 Show how Zener diode works as regulator. (CO2)

### SECTION-D

**Note:** Long answer type questions. Attempt any two questions out of three questions. (2x10=20)

- Q.36 Draw & explain in detail the Energy band diagram of metals, semiconductors & insulators. (CO1)
- Q.37 Show how phase reversal of signal takes place in the output of single stage amplifier? (CO5)
- Q.38 Explain the operating principle of FET by drawing its characteristics. (CO6)

(**Note:** Course outcome/CO is for office use only)

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